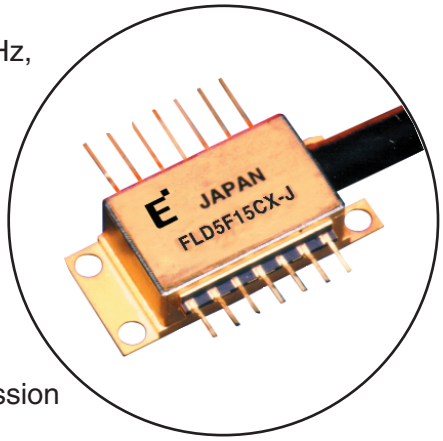
1,550nm DWDM Direct Modulation DFB Laser

FLD5F15CX-J

FEATURES

- Direct Modulation Laser for WDM systems
- Optimized for Long Distance Transmission (Dispersion 1800ps/nm)
- Peak wavelength 1527.99 to 1563.05nm (C-band: 191.8 to 196.2THz, 100GHz spacing)
- Output Power: 10mW
- 14-pin Butterfly type package
- Built-in Optical Isolator, Power Monitor PIN-PD, Thermistor, and Cooler
- Single Mode Fiber



APPLICATIONS

This laser is intended for the application of 2.5 Gb/s long haul Dense Wavelength Division Multiplexing (DWDM). Transmission spans of 100 km (1800ps/nm) are possible.

DESCRIPTION

The laser is a high power laser capable of 2.5 Gb/s transmission.
It is packaged in a “butterfly” type module. The module employs a high efficiency optical coupling system, coupling the laser output through a built-in optical isolator into a single mode fiber pigtail. The module also includes a monitor photodiode, a thermoelectric cooler (TEC), and thermistor. This device is designed for use in DWDM direct modulation transmission systems. Selected wavelengths specified to the ITU-T grid are available.

ABSOLUTE MAXIMUM RATINGS (T_C=25°C, unless otherwise specified)

Parameter	Symbol	Condition	Ratings		Unit
			Min.	Max.	
Storage Temperature	T_{stg}	-	-40	+85	°C
Operating Case Temperature	T_{op}	-	-20	+70	°C
Optical Output Power	P_f	CW	-	12	mW
LD Forward Current	I_F	CW	-	150	mA
LD Reverse Voltage	V_R	-	-	2	V
PD Reverse Voltage	V_{DR}	-	-	20	V
PD Forward Current	I_{PF}	-	-	10	mA
Cooler Voltage	V_c	Cooling	-	2.5	V
		Heating	-2.5	-	
Cooler Current	I_c	Cooling	-	1.4	A
		Heating	-0.9	-	
Thermistor Temperature	T_{th}	ATC Operation	-20	+70	°C
Lead Soldering Time	T_{sold}	260°C	-	10	sec
Environmental Operating Humidity	X_{op}	Top<30°C	-	95	%
Environmental Storage Humidity	X_{st}	Tstg<30°C	-	95	%

OPTICAL AND ELECTRICAL CHARACTERISTICS (T_L=T_{set}, T_c=25°C, BOL, unless otherwise specified)

Parameter	Symbol	Test Conditions	Limits			Unit
			Min.	Typ.	Max.	
Laser Set Temperature	T_{set}	-	20	-	35	°C
Threshold Current	I_{th}	CW	4	-	40	mA
Forward Voltage	V_{FDC}	CW, I_F=30 mA, pin 12, 13	-	1.6	1.75	V
Series Resistance	R_S	CW, pin 12, 13	22	25	28	Ω
Optical Output Power	P_f	CW	10.0	-	-	mW
Slope Efficiency	η	CW, Pf=10mW	0.14	-	-	mW/mA
Threshold Power	P_{th}	I_F=I_{th}, CW	-	-	150	μW
Tracking Error (Note 1)	TE	Pf=10mW, T_c=-20 to 70°C, Im-APC	-0.5	-	+0.5	dB
Monitor Current	I_m	CW, Pf=10mW, V_{DR}=5V	0.25	-	2.5	mA
Photodiode Dark Current	I_D	V_{DR}=5V	-	2	100	nA
Photodiode Capacitance	C_t	V_{DR}=5V, f=1 MHz	-	-	10	pF
Photodiode Cutoff Frequency	f_{cm}	V_{DR}=5V, 50Ω load	100	-	-	MHz
Peak Wavelength	λ_p	Note (2)	Note (4)			nm
Wavelength Drift (after 20 yrs)	Δλ	Note (2)	-100	-	+100	pm
Wavelength Stabilty with Case Temperature	dλ/dTc	Tc=-20 to 70°C	-1.0	-	+1.0	pm/°C
Side Mode Suppression	Sr	Note (2)	35	40	-	dB
Spectral Width (-20dB)	δλ	Note (2)	-	-	0.5	nm
Rise/Fall Time	T_r, T_f	20% to 80%	-	-	0.125	nsec
Cutoff Frequency	f_c	P_f=10mW, -3 dB	3.5	-	-	GHz
RF Return Loss	S_{11}	f=50 MHz ~ 2 GHz	8	-	-	dB
		f=2 GHz ~ 3 GHz	6	-	-	dB
		f=3 GHz ~ 5 GHz	3	-	-	dB
Optical Isolation	I_S	Tc=-20 to 70°C	25	35	-	dB
Relative Intensity Noise	RIN	f=2.5 GHz Pf=10 mW, ORL=24 dB	-	-	-140	dB/Hz
Kink	Kns	up to 12mW	No Kink			-
Dispersion Penalty	dP	Note (3)	-	-	2.0	dB

Note 1. TE=10*log{pf(Tcase)/Pf(Tc=25°C)}(dB)
Note 2. 2.5 Gb/s NRZ, Ppeak=10.0mW, Rext=8.2dB, PRBS=2^{23}-1,
Note 3. Bit rate=2.48832 Gb/s, PRBS=2^{23}-1, Dispersion=1,800 ps/nm, Ppeak=10mW, Rext=8.2dB
Decision point: Center of Back-to-Back at 10^{-9}, No Floor,
Receiver: Eudyna Standard Receiver
Note 4. The selected wavelengths available are listed in Fig. 8

TEC AND THERMISTOR CHARACTERISTICS (T_L=T_{set}, T_C=25°C, BOL, unless otherwise specified)

Parameter	Symbol	Test Conditions	Limit			Unit
			Min.	Typ.	Max.	
Cooler Current	I_C	T_L=Tset, P_f=10mW, Tc=70°C	-	-	1.0	A
Cooler Voltage	V_C		-	-	2.4	V
Cooler Power	P_C		-	-	2.4	W
Thermistor Resistance	Rtr	TL=25°C	9.5	10.0	10.5	kΩ
Thermistor B Constant	B		3,270	3,450	3,630	K

Fig. 1 Forward Current vs Output Power

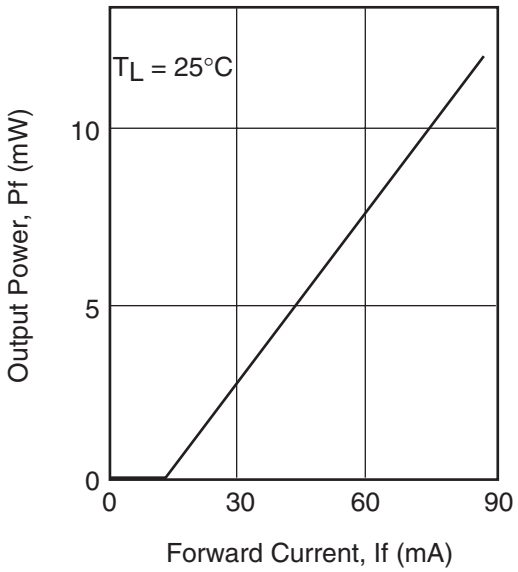


Fig. 2 Frequency Response

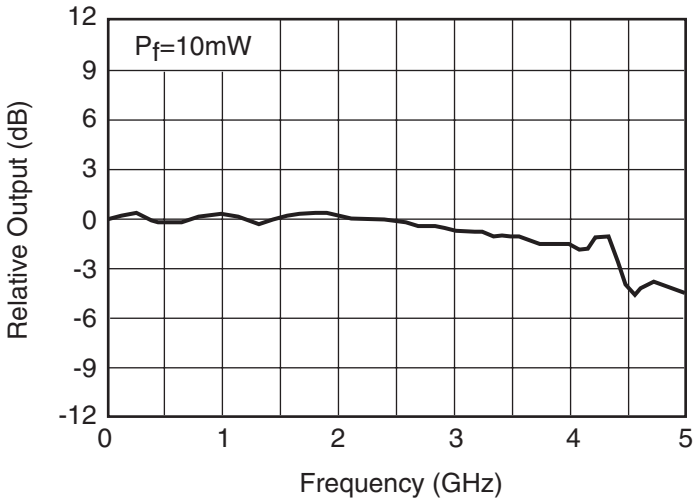


Fig. 3 RF Return Loss

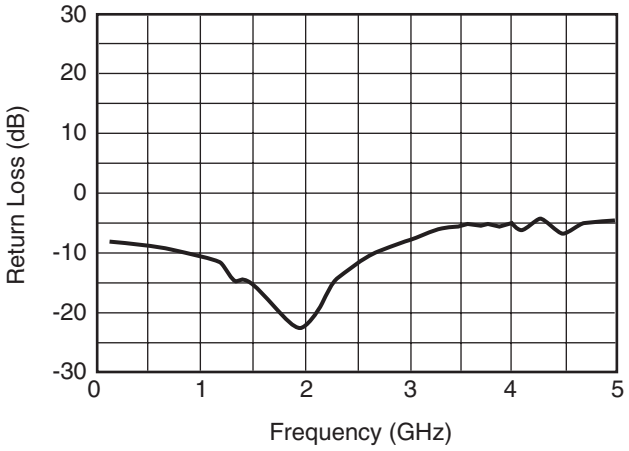


Fig. 4 Cooler Voltage -Current

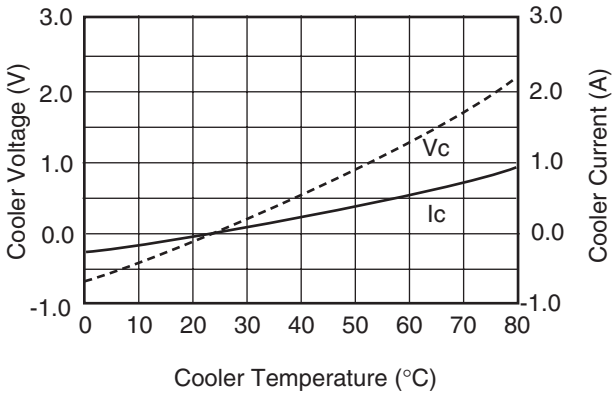


Fig. 5 Spectrum

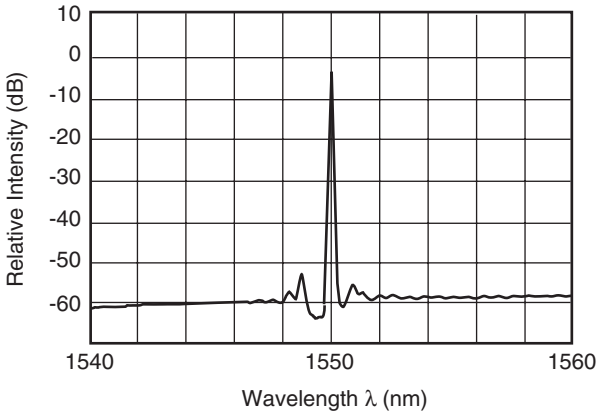


Fig. 6 Temperature Dependance of Wavelength (ACC Operation)

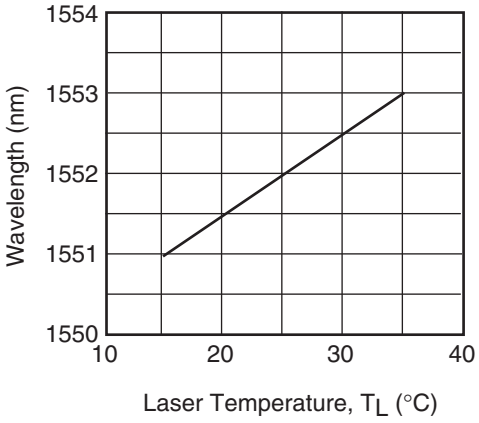


Fig. 7 Transmission Characteristics

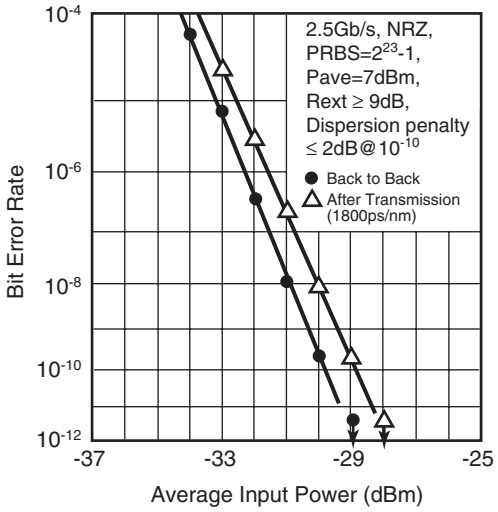
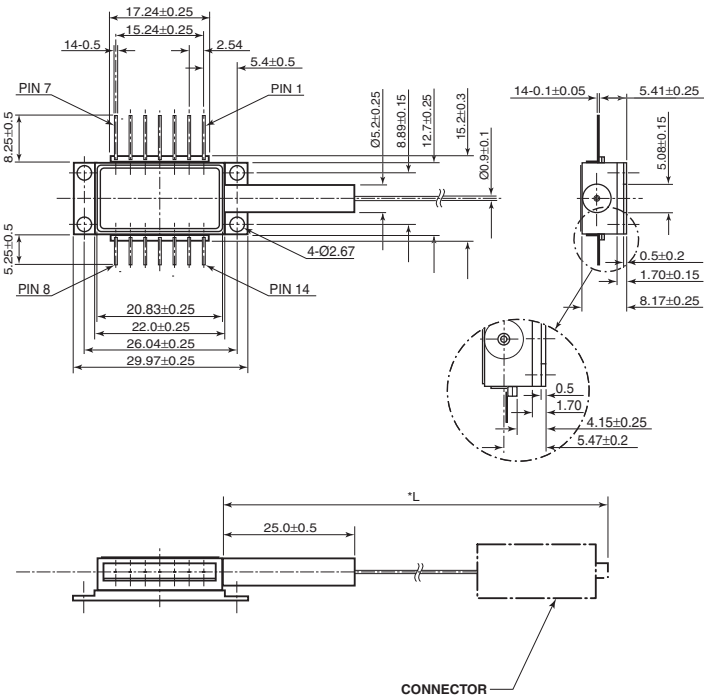


Fig. 8 Wavelength Table

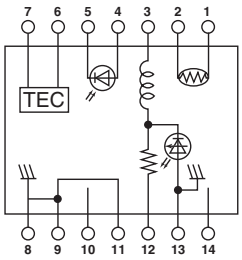
Part Number	Wavelength (nm) (TL=Tset) (in vacuum)	Tolerance (nm)
FLD5F15CX-J9620	1527.99	±0.1
-J9610	1528.77	±0.1
-J9600	1529.55	±0.1
-J9590	1530.33	±0.1
-J9580	1531.12	±0.1
-J9570	1531.90	±0.1
-J9560	1532.68	±0.1
-J9550	1533.47	±0.1
-J9540	1534.25	±0.1
-J9530	1535.04	±0.1
-J9520	1535.82	±0.1
-J9510	1536.61	±0.1
-J9500	1537.40	±0.1
-J9490	1538.19	±0.1
-J9480	1538.98	±0.1
-J9470	1539.77	±0.1
-J9460	1540.56	±0.1
-J9450	1541.35	±0.1
-J9440	1542.14	±0.1
-J9430	1542.94	±0.1
-J9420	1543.73	±0.1
-J9410	1544.53	±0.1
-J9400	1545.32	±0.1
-J9390	1546.12	±0.1
-J9380	1546.92	±0.1
-J9370	1547.72	±0.1
-J9360	1548.51	±0.1
-J9350	1549.32	±0.1
-J9340	1550.12	±0.1
-J9330	1550.92	±0.1
-J9320	1551.72	±0.1
-J9310	1552.52	±0.1
-J9300	1553.33	±0.1
-J9290	1554.13	±0.1
-J9280	1554.94	±0.1
-J9270	1555.75	±0.1
-J9260	1556.55	±0.1
-J9250	1557.36	±0.1
-9240	1558.17	±0.1
-J9230	1558.98	±0.1
-J9220	1559.79	±0.1
-J9210	1560.61	±0.1
-J9200	1561.42	±0.1
-J9190	1562.23	±0.1
-J9180	1563.05	±0.1

"CX" PACKAGE **UNIT: mm**



Grounded Type

PIN #	FUNCTION
1.	Thermistor
2.	Thermistor
3.	Laser DC Bias (-)
4.	Monitor (Anode)
5.	Monitor (Cathode)
6.	Thermoelectric Cooler (+)
7.	Thermoelectric Cooler (-)
8.	Case Ground
9.	Case Ground
10.	N.C.
11.	Case Ground
12.	Laser Modulation (-)
13.	Case Ground
14.	N.C.



For further information please contact:

Eudyna Devices USA Inc.
2355 Zanker Rd.
San Jose, CA 95131-1138, U.S.A.
TEL: (408) 232-9500
FAX: (408) 428-9111
www.us.eudyna.com

Eudyna Devices Europe Ltd.
Network House
Norreys Drive
Maidenhead, Berkshire SL6 4FJ
United Kingdom
TEL: +44 (0) 1628 504800
FAX: +44 (0) 1628 504888

Eudyna Devices Asia Pte Ltd.
Hong Kong Branch
Rm. 1101, Ocean Centre, 5 Canton Rd.
Tsim Sha Tsui, Kowloon, Hong Kong
TEL: +852-2377-0227
FAX: +852-2377-3921

Eudyna Devices Inc.
Sales Division
1, Kanai-cho, Sakae-ku
Yokohama, 244-0845, Japan
TEL: +81-45-853-8156
FAX: +81-45-853-8170

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- **Observe government laws and company regulations when discarding this product. This product must be discarded in accordance with methods specified by applicable hazardous waste procedures.**